# 2SB0873 (2SB873)

# Silicon PNP epitaxial planar type

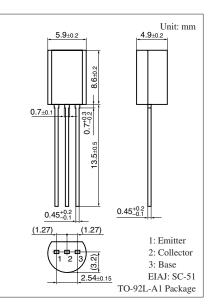
For low-frequency power amplification For DC-DC converter For stroboscope

#### Features

- Low collector-emitter saturation voltage  $V_{CE(sat)}$
- $\bullet$  Large collector current  $I_{C}$

Absolute maximum matings $T_a = 25$ C						
Parameter	Symbol	Rating	Unit			
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	-30	V			
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	-20	V			
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	-7	V			
Collector current	I <sub>C</sub>	-5	А			
Peak collector current	I <sub>CP</sub>	-10	А			
Collector power dissipation	P <sub>C</sub>	1	W			
Junction temperature	Tj	150	°C			
Storage temperature	T <sub>stg</sub>	-55 to +150	°C			

#### Absolute Maximum Ratings $T_a = 25^{\circ}C$



### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{\rm C} = -1  {\rm mA},  I_{\rm B} = 0$	-20			V
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	$I_{\rm E} = -10 \ \mu A, \ I_{\rm C} = 0$	-7			V
Collector-base cutoff current (Emitter open)	I <sub>CBO</sub>	$V_{CB} = -10 \text{ V}, I_E = 0$			-100	nA
Emitter-base cutoff current (Collector open)	I <sub>EBO</sub>	$V_{EB} = -5 V, I_C = 0$			-100	nA
Forward current transfer ratio *1, 2	h <sub>FE</sub>	$V_{CE} = -2 V, I_C = -2 A$	90		625	
Collector-emitter saturation voltage *1	V <sub>CE(sat)</sub>	$I_{\rm C} = -3$ A, $I_{\rm B} = -0.1$ A			-1	V
Transition frequency	f <sub>T</sub>	$V_{CB} = -6 \text{ V}, I_E = 50 \text{ mA}, f = 200 \text{ MHz}$		120		MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -20 \text{ V}, I_E = 0, f = 1 \text{ MHz}$			85	pF
(Common-emitter reverse transfer)						

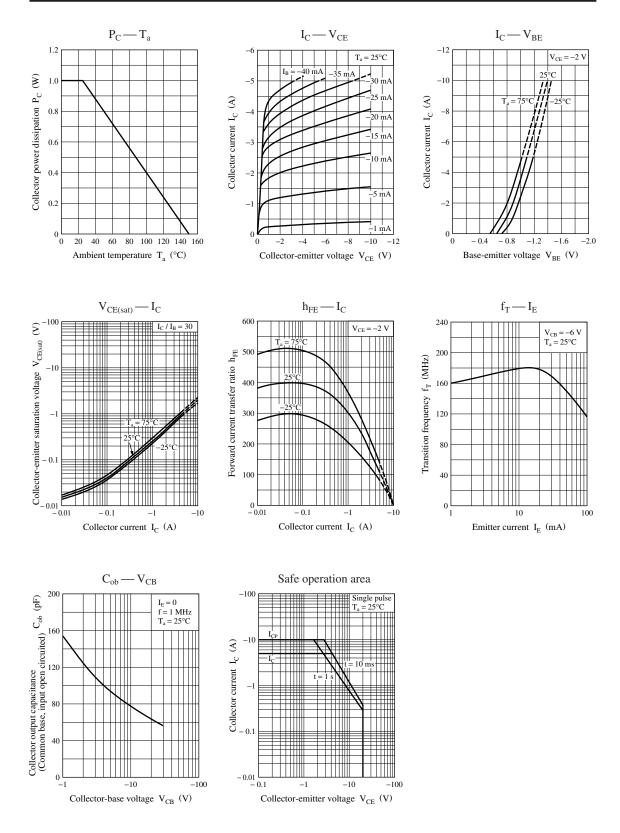
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*1: Pulse measurement

\*2: Rank classification

Rank	Р	Q	R
h <sub>FE</sub>	90 to 135	120 to 205	180 to 625

Note) The part number in the parenthesis shows conventional part number.



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